National Semiconductor

LM35 Precision Centigrade Temperature Sensors

General Description

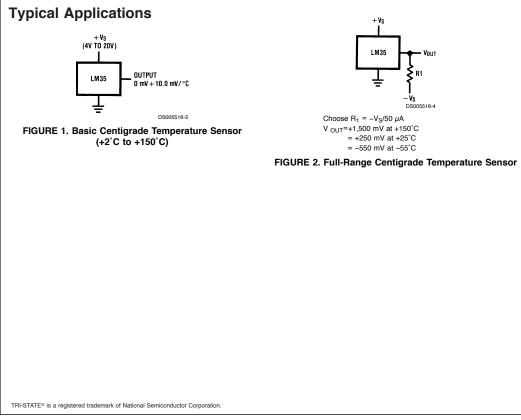
The LM35 series are precision integrated-circuit temperature sensors, whose output voltage is linearly proportional to the Celsius (Centigrade) temperature. The LM35 thus has an advantage over linear temperature sensors calibrated in

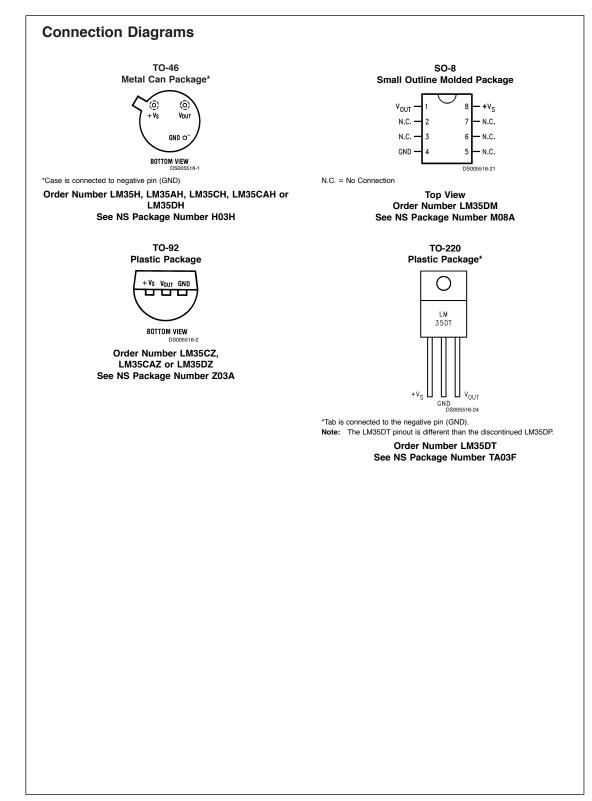
[°] Kelvin, as the user is not required to subtract a large constant voltage from its output to obtain convenient Centigrade scaling. The LM35 does not require any external calibration or trimming to provide typical accuracies of $\pm 1/4^{\circ}$ C at room temperature and $\pm 3/4^{\circ}$ C over a full –55 to +150°C temperature range. Low cost is assured by trimming and calibration at the wafer level. The LM35's low output impedance, linear output, and precise inherent calibration make interfacing to readout or control circuitry especially easy. It can be used with single power supplies, or with plus and minus supplies. As it draws only 60 μ A from its supply, it has very low self-heating, less than 0.1°C in still air. The LM35 is rated to operate over a –55° to +150°C temperature range, while the LM35C is rated for a –40° to +110°C range (–10° with improved accuracy). The LM35 series is available packaged in hermetic TO-46 transistor packages, while the LM35C, LM35CA, and LM35D are also available in the plastic TO-92 transistor package. The LM35D is also available in an 8-lead surface mount small outline package and a plastic TO-220 package.

Features

- Calibrated directly in ° Celsius (Centigrade)
- Linear + 10.0 mV/°C scale factor
- 0.5°C accuracy guaranteeable (at +25°C)
- Rated for full –55° to +150°C range
- Suitable for remote applications
- Low cost due to wafer-level trimming
- Operates from 4 to 30 volts
- Less than 60 µA current drain
- Low self-heating, 0.08°C in still air
- Nonlinearity only ±1/4°C typical
- Low impedance output, 0.1 Ω for 1 mA load

July 1999





Absolute Maximum Ratings (Note 10)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

+35V to -0.2V
+6V to -1.0V
10 mA
–60°C to +180°C
–60°C to +150°C
–65°C to +150°C
–65°C to +150°C
300°C

TO-92 and TO-220 Package, (Soldering, 10 seconds) SO Package (Note 12)	260°C
Vapor Phase (60 seconds)	215°C
Infrared (15 seconds)	220°C
ESD Susceptibility (Note 11)	2500V
Specified Operating Temperature Rang (Note 2)	e: T_{MIN} to T_{MAX}
LM35, LM35A	-55°C to +150°C
LM35C, LM35CA	-40°C to +110°C
LM35D	0°C to +100°C

Electrical Characteristics

(Notes 1, 6)

		LM35A			LM35CA			
Parameter	Conditions		Tested	Design		Tested	Design	Units
		Typical	Limit	Limit	Typical	Limit	Limit	(Max.)
			(Note 4)	(Note 5)		(Note 4)	(Note 5)	
Accuracy	T _A =+25°C	±0.2	±0.5		±0.2	±0.5		°C
(Note 7)	T _A =-10°C	±0.3			±0.3		±1.0	°C
	T _A =T _{MAX}	±0.4	±1.0		±0.4	±1.0		°C
	T _A =T _{MIN}	±0.4	±1.0		±0.4		±1.5	°C
Nonlinearity	T _{MIN} ≤T _A ≤T _{MAX}	±0.18		±0.35	±0.15		±0.3	°C
(Note 8)								
Sensor Gain	T _{MIN} ≤T _A ≤T _{MAX}	+10.0	+9.9,		+10.0		+9.9,	mV/°C
(Average Slope)			+10.1				+10.1	
Load Regulation	T _A =+25°C	±0.4	±1.0		±0.4	±1.0		mV/m/
(Note 3) 0≤I _L ≤1 mA	T _{MIN} ≤T _A ≤T _{MAX}	±0.5		±3.0	±0.5		±3.0	mV/m/
Line Regulation	T _A =+25°C	±0.01	±0.05		±0.01	±0.05		mV/V
(Note 3)	4V≤V _S ≤30V	±0.02		±0.1	±0.02		±0.1	mV/V
Quiescent Current	V _S =+5V, +25°C	56	67		56	67		μA
(Note 9)	V _s =+5V	105		131	91		114	μA
	V _S =+30V, +25°C	56.2	68		56.2	68		μA
	V _s =+30V	105.5		133	91.5		116	μA
Change of	4V≤V _S ≤30V, +25°C	0.2	1.0		0.2	1.0		μA
Quiescent Current	4V≤V _S ≤30V	0.5		2.0	0.5		2.0	μA
(Note 3)								
Temperature		+0.39		+0.5	+0.39		+0.5	µA/°C
Coefficient of								
Quiescent Current								
Minimum Temperature	In circuit of	+1.5		+2.0	+1.5		+2.0	°C
for Rated Accuracy	Figure 1, I _L =0							
Long Term Stability	T J=TMAX, for	±0.08			±0.08			°C
	1000 hours							

Parameter			LM35		L	.M35C, LM3	5D	
	Conditions	Tested		Design		Tested	Design	Units
		Typical	Limit	Limit	Typical	Limit	Limit	(Max.)
			(Note 4)	(Note 5)		(Note 4)	(Note 5)	
Accuracy,	T _A =+25°C	±0.4	±1.0		±0.4	±1.0		°C
LM35, LM35C	T _A =-10°C	±0.5			±0.5		±1.5	°C
(Note 7)	T _A =T _{MAX}	±0.8	±1.5		±0.8		±1.5	°C
	T _A =T _{MIN}	±0.8		±1.5	±0.8		±2.0	°C
Accuracy, LM35D	T _A =+25°C				±0.6	±1.5		°C
(Note 7)	T _A =T _{MAX}				±0.9		±2.0	°C
	T _A =T _{MIN}				±0.9		±2.0	°C
Nonlinearity	T _{MIN} ≤T _A ≤T _{MAX}	±0.3		±0.5	±0.2		±0.5	°C
(Note 8)								
Sensor Gain	T _{MIN} ≤T _A ≤T _{MAX}	+10.0	+9.8,		+10.0		+9.8,	mV/°C
(Average Slope)			+10.2				+10.2	
Load Regulation	T _A =+25°C	±0.4	±2.0		±0.4	±2.0		mV/mA
(Note 3) 0≤l _L ≤1 mA	T _{MIN} ≤T _A ≤T _{MAX}	±0.5		±5.0	±0.5		±5.0	mV/mA
Line Regulation	T _A =+25°C	±0.01	±0.1		±0.01	±0.1		mV/V
(Note 3)	4V≤V _S ≤30V	±0.02		±0.2	±0.02		±0.2	mV/V
Quiescent Current	V _S =+5V, +25°C	56	80		56	80		μΑ
(Note 9)	V _s =+5V	105		158	91		138	μA
	V _S =+30V, +25°C	56.2	82		56.2	82		μA
	V _s =+30V	105.5		161	91.5		141	μΑ
Change of	4V≤V _S ≤30V, +25°C	0.2	2.0		0.2	2.0		μΑ
Quiescent Current	4V≤V _S ≤30V	0.5		3.0	0.5		3.0	μA
(Note 3)								
Temperature		+0.39		+0.7	+0.39		+0.7	µA/°C
Coefficient of								
Quiescent Current								
Minimum Temperature	In circuit of	+1.5		+2.0	+1.5		+2.0	°C
for Rated Accuracy	Figure 1, I _L =0							
Long Term Stability	T _J =T _{MAX} , for 1000 hours	±0.08			±0.08			°C

Note 1: Unless otherwise noted, these specifications apply: $-55^{\circ}C \le T_J \le +150^{\circ}C$ for the LM35 and LM35A; $-40^{\circ} \le T_J \le +110^{\circ}C$ for the LM35C and LM35CA; and $0^{\circ} \le T_J \le +100^{\circ}C$ for the LM35D. $V_S = +5Vdc$ and $I_{LOAD} = 50 \ \mu$ A, in the circuit of *Figure 2*. These specifications also apply from $+2^{\circ}C$ to T_{MAX} in the circuit of *Figure 1*. Specifications in **boldface** apply over the full rated temperature range.

Note 2: Thermal resistance of the TO-46 package is 400°C/W, junction to ambient, and 24°C/W junction to case. Thermal resistance of the TO-92 package is 180°C/W junction to ambient. Thermal resistance of the small outline molded package is 220°C/W junction to ambient. Thermal resistance of the TO-220 package is 90°C/W junction to ambient. For additional thermal resistance information see table in the Applications section.

Note 3: Regulation is measured at constant junction temperature, using pulse testing with a low duty cycle. Changes in output due to heating effects can be computed by multiplying the internal dissipation by the thermal resistance.

Note 4: Tested Limits are guaranteed and 100% tested in production.

Note 5: Design Limits are guaranteed (but not 100% production tested) over the indicated temperature and supply voltage ranges. These limits are not used to calculate outgoing quality levels.

Note 6: Specifications in boldface apply over the full rated temperature range.

Note 7: Accuracy is defined as the error between the output voltage and 10mv/²C times the device's case temperature, at specified conditions of voltage, current, and temperature (expressed in *C).

Note 8: Nonlinearity is defined as the deviation of the output-voltage-versus-temperature curve from the best-fit straight line, over the device's rated temperature range.

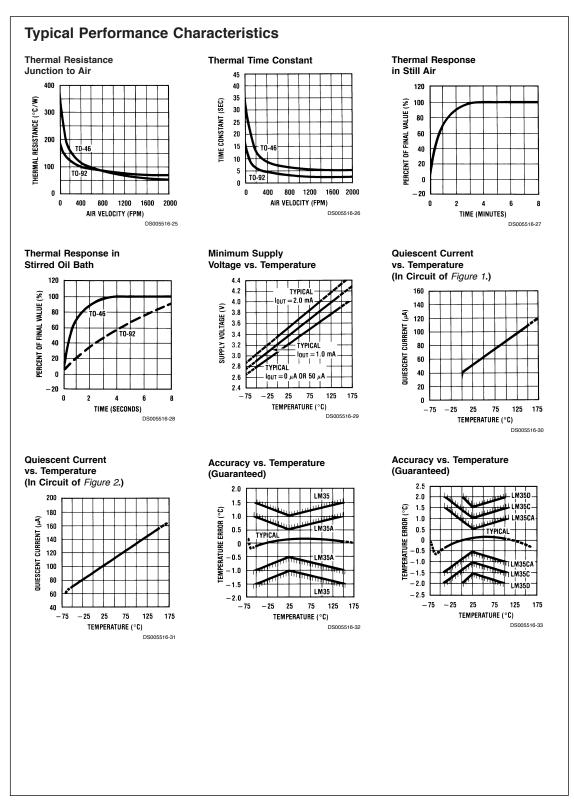
Note 9: Quiescent current is defined in the circuit of Figure 1.

Note 10: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. DC and AC electrical specifications do not apply when operating the device beyond its rated operating conditions. See Note 1.

Note 11: Human body model, 100 pF discharged through a 1.5 k Ω resistor.

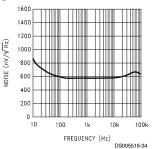
Note 12: See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" or the section titled "Surface Mount" found in a current National Semiconductor Linear Data Book for other methods of soldering surface mount devices.

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Typical Performance Characteristics (Continued)

Noise Voltage

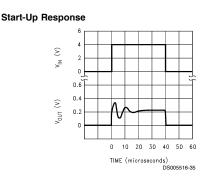


Applications

The LM35 can be applied easily in the same way as other integrated-circuit temperature sensors. It can be glued or cemented to a surface and its temperature will be within about 0.01°C of the surface temperature.

This presumes that the ambient air temperature is almost the same as the surface temperature; if the air temperature were much higher or lower than the surface temperature, the actual temperature of the LM35 die would be at an intermediate temperature between the surface temperature and the air temperature. This is expecially true for the TO-92 plastic package, where the copper leads are the principal thermal path to carry heat into the device, so its temperature might be closer to the air temperature than to the surface temperature.

To minimize this problem, be sure that the wiring to the LM35, as it leaves the device, is held at the same temperature as the surface of interest. The easiest way to do this is to cover up these wires with a bead of epoxy which will insure that the leads and wires are all at the same temperature as the surface, and that the LM35 die's temperature will not be affected by the air temperature.



The TO-46 metal package can also be soldered to a metal surface or pipe without damage. Of course, in that case the V- terminal of the circuit will be grounded to that metal. Alternatively, the LM35 can be mounted inside a sealed-end into a threaded hole in a tank. As with any IC, the LM35 and accompanying wiring and circuits must be kept insulated and dry, to avoid leakage and corrosion. This is especially true if the circuit may operate at cold temperatures where condensation can occur. Printed-circuit coatings and varnishes such as Humiseal and epoxy paints or dips are often used to insure that moisture cannot corrode the LM35 or its connections.

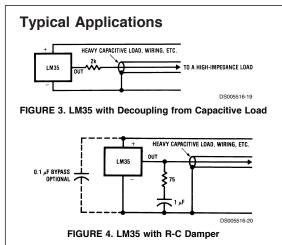
These devices are sometimes soldered to a small light-weight heat fin, to decrease the thermal time constant and speed up the response in slowly-moving air. On the other hand, a small thermal mass may be added to the sensor, to give the steadiest reading despite small deviations in the air temperature.

Temperature Rise of LM35 Due To Self-heating (Thermal Resistance, θ_{JA})

	TO-46.	TO-46*.	TO-92.	TO-92**.	SO-8	SO-8**	TO-220
	no heat sink	small heat fin	no heat sink	small heat fin	no heat sink	small heat fin	no heat sink
Still air	400°C/W	100°C/W	180°C/W	140°C/W	220°C/W	110°C/W	90°C/W
Moving air	100°C/W	40°C/W	90°C/W	70°C/W	105°C/W	90°C/W	26°C/W
Still oil	100°C/W	40°C/W	90°C/W	70°C/W			
Stirred oil	50°C/W	30°C/W	45°C/W	40°C/W			
(Clamped to metal,							
Infinite heat sink)	(24	4°C/W)			(5	5°C/W)	

*Wakefield type 201, or 1" disc of 0.020" sheet brass, soldered to case, or similar,

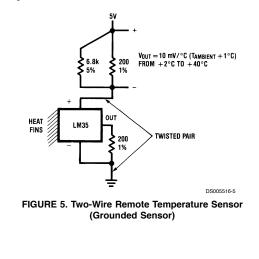
**TO-92 and SO-8 packages glued and leads soldered to 1" square of 1/16" printed circuit board with 2 oz. foil or similar.

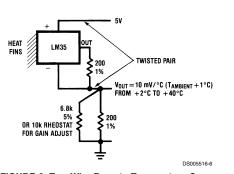


CAPACITIVE LOADS

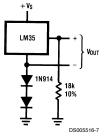
Like most micropower circuits, the LM35 has a limited ability to drive heavy capacitive loads. The LM35 by itself is able to drive 50 pf without special precautions. If heavier loads are anticipated, it is easy to isolate or decouple the load with a resistor; see *Figure 3*. Or you can improve the tolerance of capacitance with a series R-C damper from output to ground; see *Figure 4*.

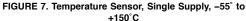
When the LM35 is applied with a 200 Ω load resistor as shown in *Figure 5, Figure 6* or *Figure 8* it is relatively immune to wiring capacitance because the capacitance forms a bypass from ground to input, not on the output. However, as with any linear circuit connected to wires in a hostile environment, its performance can be affected adversely by intense electromagnetic sources such as relays, radio transmitters, motors with arcing brushes, SCR transients, etc, as its wiring can act as a receiving antenna and its internal junctions can act as rectifiers. For best results in such cases, a bypass capacitor from V_{IN} to ground and a series R-C damper such as 75 Ω in series with 0.2 or 1 μ F from output to ground are often useful. These are shown in *Figure 13, Figure 14*, and *Figure 16*.











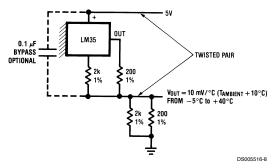
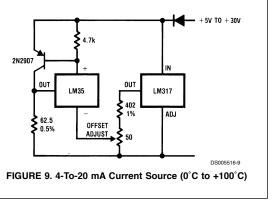
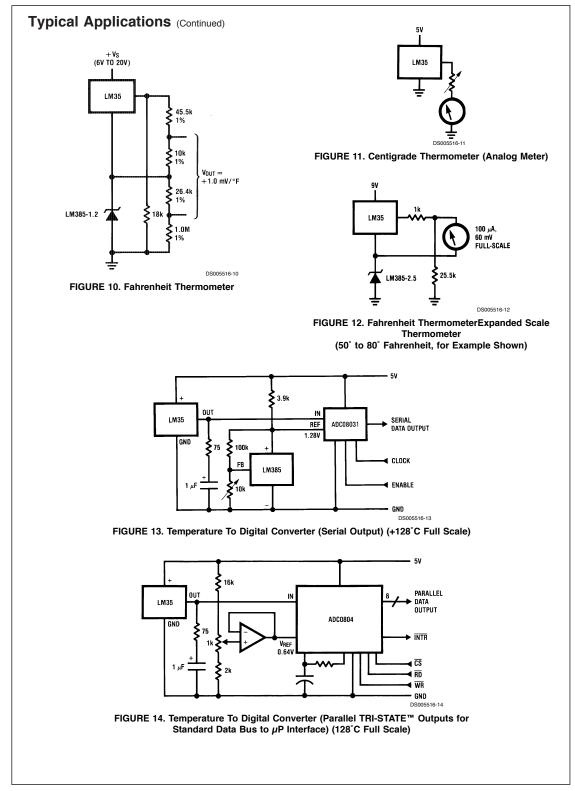
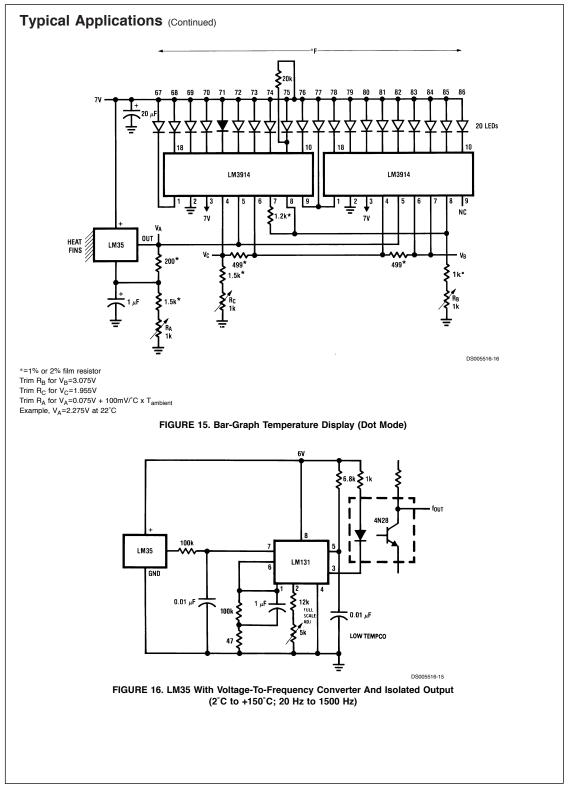


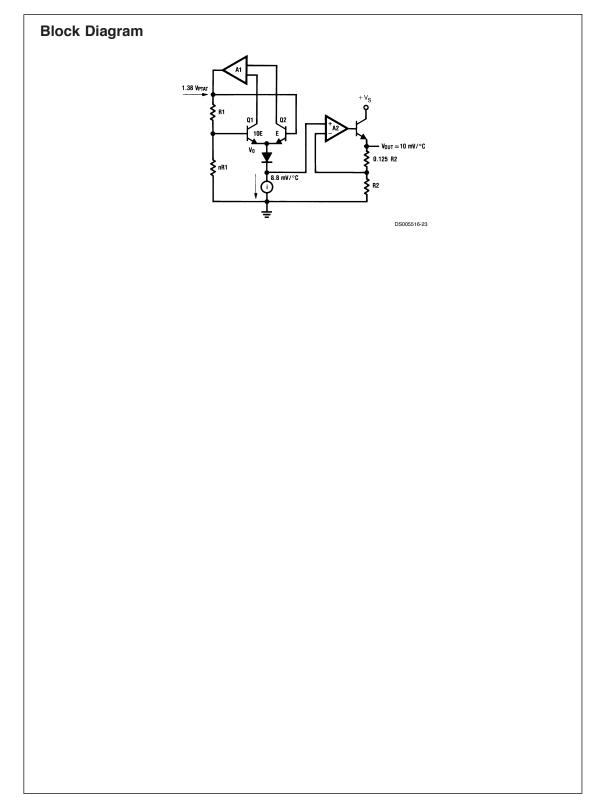
FIGURE 8. Two-Wire Remote Temperature Sensor (Output Referred to Ground)

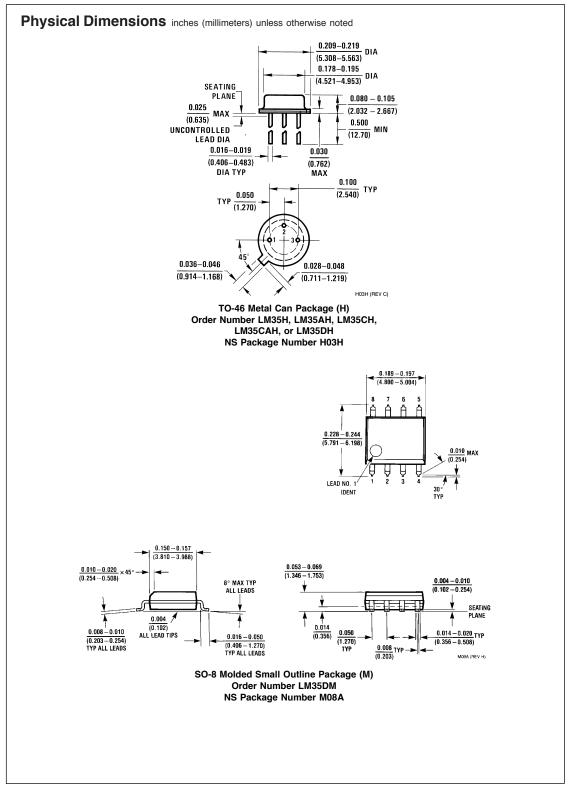


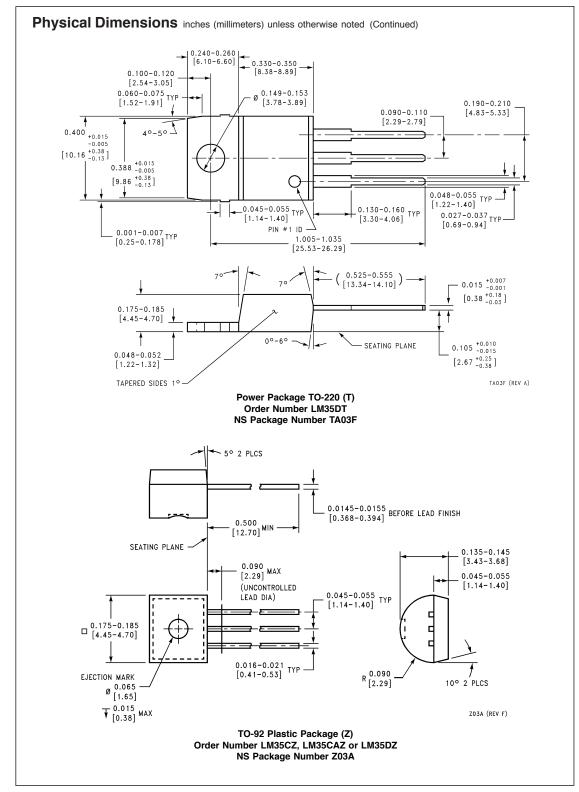


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